

August 1993 Revised May 2005

74VHC541

Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHC541 is an advanced high-speed CMOS device fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The VHC541 is an octal buffer/line driver designed to be employed as memory and address drivers, clock drivers and bus oriented transmitter/receivers.

This device is similar in function to the VHC244 while providing flow-through architecture (inputs on opposite side from outputs). This pinout arrangement makes this device especially useful as an output port for microprocessors, allowing ease of layout and greater PC board density.

An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed: t_{PD} = 3.5 ns (typ) at V_{CC} = 5V
- \blacksquare Low power dissipation: I_{CC} = $4~\mu A$ (max) at T_A = $25^{\circ}C$
- \blacksquare High noise immunity: $\text{V}_{\text{NIH}} = \text{V}_{\text{NIL}} = 28\% \text{ V}_{\text{CC}}$ (min)
- Power down protection is provided on all inputs
- Low noise: V_{OLP} = 0.9V (typ)
- Pin and function compatible with 74HC541

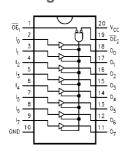
Ordering Code:

Order Number	Package Number	Package Description
74VHC541M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC541SJ	M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC541N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

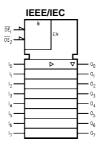
Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

Connection Diagram



Logic Symbol



Pin Descriptions

Pin Names		Descriptions					
	\overline{OE}_1 , \overline{OE}_2	3-STATE Output Enable Inputs					
	I ₀ - I ₇	Inputs					
	O ₀ - O ₇	3-STATE Outputs					

Truth Table

	Outputs			
OE ₁	OE ₂	ı		
L	L	Н	Н	
Н	Χ	X	Z	
Х	Н	X	Z	
L	L	L	L	

H = HIGH Voltage Level X = Immaterial Z = High Impedance L = LOW Voltage Level

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V DC Input Voltage (V_{IN}) -0.5V to +7.0V DC Output Voltage (V_{OUT}) -0.5V to $V_{CC} + 0.5V$ Input Diode Current (I_{IK}) -20 mA Output Diode Current (I_{OK}) ±20 mA DC Output Current (I_{OUT}) ±25 mA DC V_{CC}/GND Current (I_{CC}) ±75 mA -65°C to +150°C Storage Temperature (T_{STG})

Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

Input Rise and Fall Time (t_r, t_f)

 $V_{CC} = 3.3 V \pm 0.3 V$ 0 ~ 100 ns/V $V_{CC} = 5.0 V \pm 0.5 V$ 0 ~ 20 ns/V

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW. They may not float

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = 25°C			T _A = -40°	-40°C to +85°C Units		Conditions	
Symbol	Farameter	(V)	Min Typ Max		Min Max		Ollits	Conditions		
V _{IH}	HIGH Level Input	2.0	1.50			1.50		V		
	Voltage	3.0 - 5.5	0.7 V _{CC}		Be	0.7 V _{CC}		V		
V _{IL}	LOW Level Input	2.0			0.50	-46	0 .50	V		
	Voltage	3.0 - 5.5			$0.3~\mathrm{V}_{\mathrm{CC}}$		0.3 V _{CC}	v		
V _{OH}	HIGH Level Output	2.0	1.9	2.0	· ·	1.9			$V_{IN} = V_{IH}$	I _{OH} = -50 μA
	Voltage	3.0	2.9	3.0		2.9		V	or V _{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		$I_{OH} = -4 \text{ mA}$
		4.5	3.94			3.80		٧		$I_{OH} = -8 \text{ mA}$
V _{OL}	LOW Level Output	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH}$	$I_{OL} = 50 \mu A$
	Voltage	3.0		0.0	0.1		0.1	V	or V _{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I _{OL} = 4 mA
		4.5			0.36		0.44	٧		$I_{OL} = 8 \text{ mA}$
l _{OZ}	3-STATE Output	5.5			±0.25		±2.5	μА	$V_{IN} = V_{IH}$ or	V _{IL}
	Off-State Current							μΑ	$V_{OUT} = V_{CC}$	or GND
I _{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μА	V _{IN} = 5.5V o	r GND
I _{CC}	Quiescent Supply Current				4.0		40.0	μА	V _{IN} = V _{CC} or	GND

Noise Characteristics

Symbol	Parameter	V _{CC}	T _A =	25°C	Units	Conditions	
	T drameter	(V)	Тур	Limits	Omio	Containons	
V _{OLP}	Quiet Output Maximum Dynamic	5.0	0.9	1.2	V	C _L = 50 pF	
(Note 3)	V _{OL}						
V _{OLV}	Quiet Output Minimum Dynamic	5.0	-0.8	-1.0	V	C _L = 50 pF	
(Note 3)	V _{OL}						
V_{IHD}	Minimum HIGH Level Dynamic	5.0		3.5	V	C _L = 50 pF	
(Note 3)	Input Voltage						
V _{ILD}	Maximum HIGH Level Dynamic	5.0		1.5	V	C _L = 50 pF	
(Note 3)	Input Voltage						

Note 3: Parameter guaranteed by design.

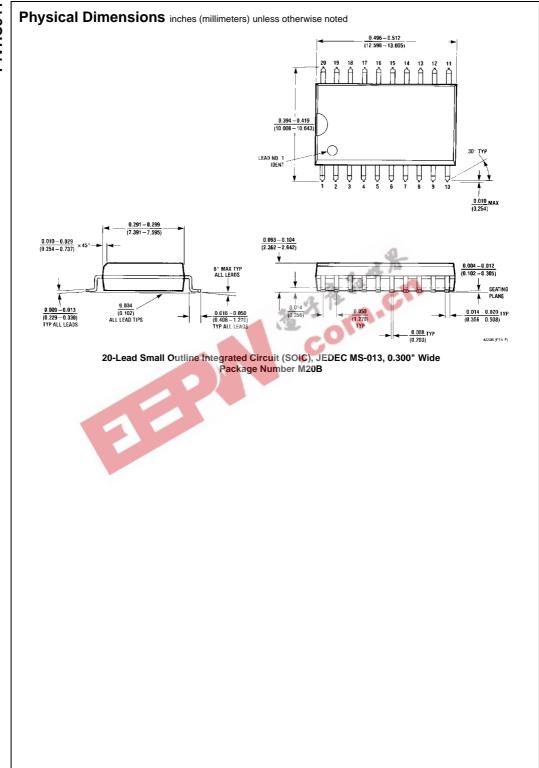
AC Electrical Characteristics

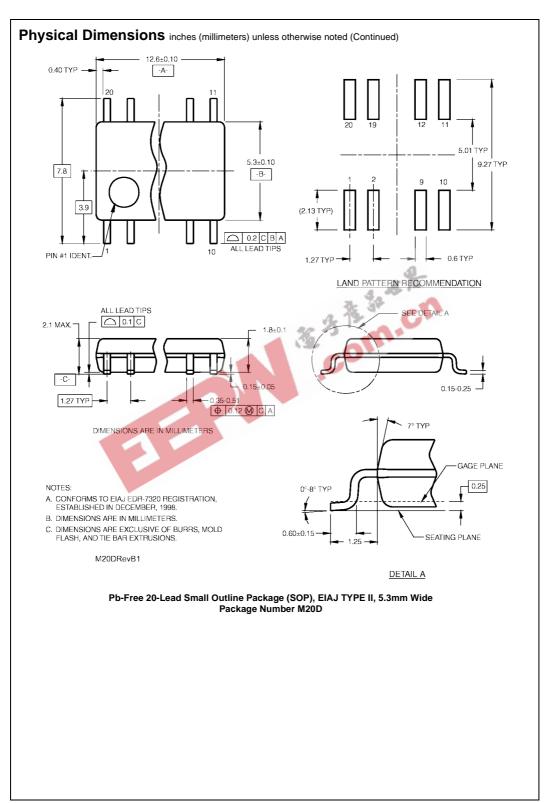
Symbol	Parameter	V _{cc}	$T_A = 25^{\circ}C$			T _A = -40°	C to +85°C	Units	Conditions	
		(V)	Min	Тур	Max	Min	Max	Oille	Conditions	
t _{PLH}	Propagation Delay	3.3 ± 0.3		5.0	7.0	1.0	8.5	ns		$C_L = 15 pF$
t _{PHL}	Time			7.5	10.5	1.0	12.0	113		$C_L = 50 pF$
		5.0 ± 0.5		3.5	5.0	1.0	6.0	ns		$C_L = 15 pF$
				5.0	7.0	1.0	8.0	115		$C_L = 50 pF$
t _{PZL}	3-STATE Output	3.3 ± 0.3		6.8	10.5	1.0	12.5	ns	$R_L = 1 k\Omega$	$C_L = 15 pF$
t _{PZH}	Enable Time			9.3	14.0	1.0	16.0	115		$C_L = 50 pF$
		5.0 ± 0.5		4.7	7.2	1.0	8.5	ns		$C_L = 15 pF$
				6.2	9.2	1.0	10.5	113		$C_L = 50 pF$
t _{PLZ}	3-STATE	3.3 ± 0.3		11.2	15.4	1.0	17.5		$R_L = 1 k\Omega$	$C_L = 50 pF$
t _{PHZ}	Output	5.0 ± 0.5		6.0	8.8	1.0	10.0	ns		$C_L = 50 pF$
	Disable Time									
toslh	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	$C_L = 50 pF$
toshl		5.0 ± 0.5			1.0		1.0	115		$C_L = 50 pF$
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open	
C _{OUT}	Output Capacitance			6			- E	pF	V _{CC} = 5.0V	
C _{PD}	Power Dissipation Capacitance			18			AM	pF	(Note 5)	

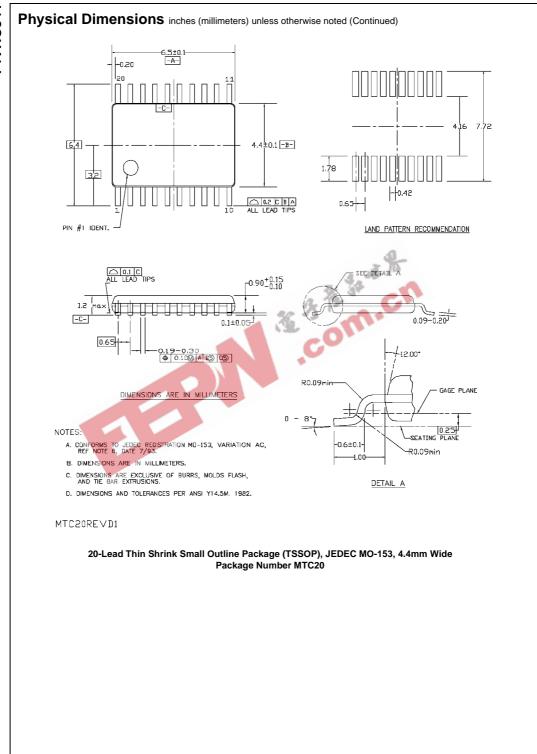
Note 4: Parameter guaranteed by design. t_{OSLH} = |t_{PLHmin}|: t_{OSHL} = |t_{PHLmin}|: Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: l_{CC} (OPR.) = C_{PD} * V_{CC} * f_{IN} + |_{CC}/8 (per bit).

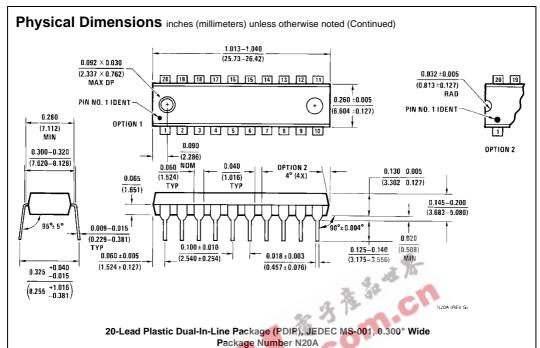
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